## NSN 5961-01-332-9506

**Fiig:** A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-9506 **Inclosure Material:** Metal **Overall Length:** 1.540 inches **Overall Height:** 0.312 inches **Overall Width:** 1.030 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Unthreaded hole **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak off-state voltage and 200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes forward current, total rms horsepower metric and 260.00 amperes peak forward surge current nanoamperes **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank and 0.5 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No